

| | Type | L # | Hit s | Search Text | DBs | Time Stamp | Comments | Error Definition | Errors |
|---|------|-----|-------|---|---|-------------------------|----------|------------------|--------|
| 2 | BRS | L2 | 9109 | semiconductor and cmos and (gate adj electrode) | USP AT; US- PGP UB; EPO ; JPO ; DER WEN T; IBM TDB | 2001/0 8/11 10:36 | | | 0 |
| 3 | BRS | L3 | 346 | 2 and (work adj function) | USP AT; US- PGP UB; EPO ; JPO ; DER WEN T; IBM TDB | 2001/0 8/11 10:37 | | | 0 |
| 4 | BRS | L4 | 308 | 3 and metal | USP AT; US- PGP UB; EPO ; JPO ; DER WEN T; IBM TDB | 2001/0 8/11 10:37 | | | 0 |